Tunable Fiber Laser Using a MEMS-Based In Plane Fabry-Pérot Filter

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Abstract—We propose a tunable erbium doped fiber laser based on a Fabry-Pérot (F-P) cavity tuned by an electrostatic actuator. The device is made of single crystalline silicon. The F-P cavity consists of two Bragg mirrors, one being displaced by a comb-drives actuator. The F-P cavity, grooves for optical fibers and electro-mechanical structure are fabricated by deep reactive ion etching on a 70 μm silicon on insulator wafer and are integrated in a ring fiber laser. The resulting tunable fiber laser has a tuning range of 35 nm in the C-band and a spectral width of less than 0.06 nm. The maximum applied voltage for full tuning of the laser is 37 V. The mechanical resonance frequency of the actuated mirror is 14.4 kHz allowing fast tuning of the laser. The maximum output power is 1.8 mW.

Index Terms—Er3+ doped fiber, Fabry-Pérot cavity, laser, micro-electro-mechanical system (MEMS), tunable.

I. INTRODUCTION

Large refractive index difference between silicon and air and low optical absorption in the telecommunication frequency range makes silicon an ideal material for optical applications. With such a large refractive index difference (3.48 for Si and 1 for air) very few periods of a Bragg grating are needed to get highly reflective broadband dielectric mirrors. By combining two of these Bragg mirrors, a Fabry-Pérot (F-P) cavity can be assembled. Recently, several applications based on in-plane F-P cavities were proposed: tunable filters [1]–[3], amplitude modulator [4], thermal-mechanical noise sensor [5] and refractive index sensor [6].

In the first part of this paper, we demonstrate a continuously tunable micro-electro-mechanical system (MEMS) F-P filter. We use a microfabrication process that allows one single lithography and etch step for the entire device fabrication. During this process, optical components, electro-mechanical parts, as well as fiber grooves needed for optical fibers alignment are fabricated. Compact filters can be designed and tuned by varying the cavity length. Wavelength tuning over 104 nm is achieved in the telecommunication C- and L-bands. In the second part of this paper, we show an application of the MEMS-based tunable F-P to a continuously tunable erbium doped ring fiber laser. Wavelength tuning over 35 nm is achieved in the telecommunication C-band.

Fiber lasers are well known and widely used in industry because of their high power and relative simplicity. They find applications as industrial cutting or welding tools [7]. Tunable fiber lasers are also good candidates as test and measurement sources for optical devices characterization because of their small spectral width, continuous tuning, and stability [8]. Wide band gain of erbium enables tuning of Er3+ fiber laser over the whole telecommunication C- and L-bands [9]. Moreover, large Er3+ gain offers the opportunity to build powerful lasers or to use lossy photonic components in the laser cavity for tuning purposes [10].

Tunable fiber lasers using different strategies have been reported previously [8], [11]–[18]. For example, tunable fiber Bragg gratings [11]–[13], [15], tunable etalons [14], [17], polarization controllers [16], and thin film filters [8] were used. The pitch of fiber Bragg gratings can be tuned either by mechanical stretching [11], [12] or heating [13]. The resulting tuning range is however very limited and the tuning mechanism is usually slow. Therefore, several different Bragg gratings are needed to increase the tuning range of the fiber laser leading to a more complicated setup that includes optical switches and circulators. Tunable etalons are external cavity components requiring complicated alignment systems and are temperature sensitive [14]. Polarization controllers exhibit limited tuning range and are difficult to integrate. In this paper, the fiber laser is tuned by a MEMS F-P cavity actuated by an electrostatic comb-drive. Comb-drive actuators are known to enable fast actuation and large displacements [19]. By combining MEMS actuation to silicon optical devices, we demonstrate a compact, fast, and wide range wavelength tunable fiber laser.

In the next sections, we introduce the optical and mechanical design of the device. Simulations describing the F-P behavior using the transfer matrix method and a gaussian beam approximation are presented. The fabrication process is detailed and optical characterizations are shown and compared to optical simulations. Finally, experimental results of the tunable filter integrated into a ring fiber laser are reported.

This paper is an extension of preliminary work published in conference proceedings [20], [21]. By comparison to the filter of [20], the tuning range is greatly increased (from
33 nm to 104 nm) and simulations are performed which allow the interpretation of the results in much greater details. By comparison to [21], the higher quality of the filter allows the tuning range of the laser to be significantly increased (from 7.7 nm to 35 nm). In fact, tuning range improvement is one of the main contribution of this paper. By comparison to the very similar filter reported in [3], the design of the MEMS actuator allows parallel displacement of the mobile mirror, which leads to a significant increase of tuning range (from 8 nm to 104 nm). The demonstration of a tunable laser would not have been possible without this novelty.

II. DEVICE DESIGN

Fig. 1 shows the fabricated device. The F-P filter is made of two Bragg mirrors made of alternated layers of silicon and air. The air cavity length is tuned by moving one of the Bragg mirrors using an electrostatic comb-drive actuator. The other mirror is static. The comb-drive and the movable mirror are suspended by a set of four springs. As the voltage applied to the contact pads is increased, the suspended comb is attracted toward the static one, bringing the mobile mirror toward the static one and shortening the cavity length. A smaller cavity length modifies the filter passband toward shorter wavelengths. When the voltage is decreased, the mirror goes back to its initial position (at $V=0$) because of the restoring force of the springs. The mechanical design of the springs and actuator is critical since the movable structure has to be highly stable to insure that the two mirrors remain parallel over the whole tuning range of the cavity. Failing to do so will generate transmission losses and broadening of the passband window. The use of a comb drive actuator suspended by four simple beam springs allows parallel displacement of the mobile mirror, which leads to an increase of the tuning range of the filter from 8 nm in [3] to 104 nm in this paper.

Light is injected and collected in and out of the filter using Corning SMF-28 optical fibers. Fibers are self-aligned on each side of the filter using fiber grooves and spring holders. This system ensures alignment loss below 1 dB [22].

III. SIMULATIONS

Calculations based on a similar method as in [3] and [6] are used to simulate the filter behavior. The algorithm considers the divergence of the gaussian beam output from a SMF-28 optical fiber. Sources of errors such as deviation of verticity of the mirrors and surface roughness are not taken into account by the model. The transmission spectrum depends on the number of layers for each Bragg mirror and on the layer thicknesses. Fig. 2 shows typical transmission spectra for four different F-P filters made of Bragg mirrors with three silicon and two air layers, and having increasing thickness of the silicon and air layers. The thickness $d$ of a layer is linked to the order $N$ by $d = N \lambda / (4n)$, where $N$ is an odd number, $\lambda$ is the wavelength, and $n$ is the refractive index of the layer. The cavity length $l$ is given by $l = M \lambda / (2n)$, where $M$ is the order the F-P cavity. The transmission spectrum of the F-P exhibits two side lobes, whose separation corresponds to the reflection bandwidth of the Bragg mirrors. One can see that as the mirror order increases the reflection bandwidth of the mirror gets smaller. Thus, a mirror with the largest possible reflection bandwidth should be made with layers of order 1. This is an important consideration since the reflection bandwidth is directly linked to the tuning range of the F-P by its finesse $F$ given by $F = \pi \sqrt{R(\lambda)} / (1 - R(\lambda))$, where $R(\lambda)$ is the wavelength dependent reflectivity. The reflectivity is low outside the reflection bandwidth leading to a poor finesse or a poor transmission. Technology is the limit for the smallest thickness of order (that can be fabricated with conventional contact ultraviolet lithography (typically 1 $\mu$m feature size) and with a good precision (higher than 10 nm). Lipson et al. [3] give a detailed description on the required precision on the fabrication parameters of such filters.

The reflectivity of a Bragg mirror is directly related to the number of dielectric layers [23]. Adding layers enhances the interference effect of the dielectric Bragg mirror, thus increasing reflectivity of the mirrors. Nevertheless, many periods Bragg mirrors do not provide the optimal properties in our configuration. Indeed, optical fibers output beam waist size is

Fig. 1. Scanning electron micrograph (SEM) of the tunable filter integrated with fiber grooves and electrical contact pads. A set of four springs holds the movable comb-drive to which the movable Bragg mirror is attached.
typically 5 \mu m at 1550 nm, and thus has significant divergence.

Many layers Bragg mirrors are highly reflective. Therefore, the lifetime of the light in the cavity is very long and losses increase dramatically as shown in Fig. 3. Using one silicon wall per Bragg mirror the transmission is close to 0 dB, but the full width at half maximum (FWHM) of the peak is 21 nm. For three silicon walls per Bragg mirror the transmission drops to \(-18\) dB and the FWHM to 0.6 nm. We found experimentally that the optimum number of layers per Bragg mirror is three silicon layers and two air layers. A beam expander could be used to circumvent the divergence effect.

For a wavelength of 1550 nm the thicknesses of the layers are designed to be 2.4 \mu m and 1.9 \mu m (corresponding to 21st and fifth orders) for silicon and air, respectively. Fig. 4 shows the simulated transmitted spectra of a F-P filter which is tuned by 88 nm from 1598 to 1510 nm. The inset numbers show the required displacement of the mirror (in nm) to generate the corresponding tuning. When there is no displacement the gap is 2.8 \mu m long and the transmission peak is located near the largest wavelengths (1600 nm). When the gap length is shortened by actuating the comb-drive the transmission peak moves toward smaller wavelength. A total displacement of 755 nm is needed to tune through the whole bandwidth of the filter. The best simulated FWHM for a transmitted peak at 1550 nm is 0.6 nm. As the peak moves closer to the bandwidth of the light beam (at trench depths of 5 \mu m to 2.155 \mu m). The numbers over each peak correspond to the displacement of the movable mirror (in nm) from its rest position.

V. Optical Characterization

A broadband source (Newport BBS-430) was used for the optical characterization of the F-P. Light is injected into the device using an SMF-28 optical fiber aligned in the fiber

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<td>RF power (W)</td>
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- ICP power (W)
- RF power (W)
- C4F8 (sccm)
- SF6 (sccm)
- D2 (sccm)
- Time (s)

The precision of this method is relatively low (a variation of 2 \mu m of the measured thickness leads to a deviation of the calculated verticality of more than 0.01°). Therefore, the reported value is an upper boundary determined by repeating the measurements several times. For the experimental results of Fig. 5, it is possible that the verticality was significantly better. This could explain that good optical results are reported despite the fact that, in [3], calculations indicate that verticality better than 89.9° is required.
Fig. 5. Superposed transmission spectra of the F-P tuned with different voltage and the corresponding fitted simulation curves (dashed). The inset numbers show the simulated displacement in nanometers of the movable mirror to fit the experimental data.

Fig. 6. Transmitted wavelength as a function of the applied voltage to the comb-drive.

groove. Another fiber is placed on the other side of the F-P to collect the transmitted light which is guided to an Agilent 86142A optical spectrum analyzer. All results presented in the following part of the paper were obtained using a filter having the configuration $21533$.

The filter is tuned by applying a voltage between the static and the movable comb using a DC voltage source. Fig. 5 shows the superposed spectra of the tuned F-P filter. The dashed curves are the simulated fit. At rest, the transmitted wavelength was 1621 nm. As we increased voltage, the transmitted peak is shifted continuously toward smaller wavelength. At a voltage of 40.7 V, the transmitted wavelength is of 1531 nm covering a tuning range of 90 nm. If the voltage is increased up to 48.5 V two transmitted peaks appear on the same curve. The separation between those peaks is the free spectral range (FSR) of the filter (104 nm). This value is the maximum tuning range of the filter. The spectral width of the filter varies between 4.4 nm and 7.6 nm and losses between $-9.46$ dB and $-24$ dB. Fig. 6 shows the transmitted wavelength as a function of applied voltage to the comb-drive. The linear part of the curve has a sensitivity of $-4.1$ nm/V.

The resonance frequency of the suspended structure was measured using a dynamic white light interferometer (Fogale Nanotech Photomap 3-D). The first mode appears at 14.4 kHz.

Fig. 7. Displacement amplitude of the movable mirror when an AC voltage is applied to the comb-drive. The first excitation mode resonance frequency is at 14.4 kHz.

To fit the optical simulations with the experimental results, we have to take into account some fabrication imperfections. The most important one comes from the over etch caused by the DRIE. During the silicon etching process, the final thicknesses of the silicon layers are smaller than the one defined on the photomask and transferred to the photoresist. This is due to lateral under etching of the silicon by the SF$_4$ ions [24].

Recalling from the definition of the thickness $d$ of a silicon wall to meet the Bragg condition, the thickness difference between two consecutive Bragg orders $N$ and $N+1$ is only 112 nm. This means that an over etch of only 112 nm in a silicon layer is enough to change $N$ from an odd to an even number. In this case, reflectivity of the Bragg mirrors drops dramatically so that the F-P performances decrease. Precise measurement and control of the over etch must be achieved to obtain good optical results. SEM photographs of a cleaved grating allowed to estimate this over etch. Using the simulation algorithm, the experimental data is fitted by varying the over etch to find its precise value. The best fit was obtained for an over etch of 710 nm per silicon layer. An over etch error on the two silicon walls facing the fiber grooves was also considered. Since these walls are exposed to a large etched area (the fiber groove), they are more exposed to ion bombardment than the inner silicon walls. As an effect, they are thinner. To have an accurate simulation, an additional 85 nm over etch was considered for these walls. Moreover, since the F-P gap is larger than the air layers of the Bragg mirrors, a larger over etch on each side of the air gap must also be taken into account. In this case, 15 nm of over etch were added in the air gap layer. The displacement of the movable Bragg mirror needed to tune the filter is finally fitted using the above-mentioned parameters. Dimensions in Fig. 5 refer to the displacement needed to tune the filter at the corresponding wavelength. A maximum experimental displacement of 629 nm is needed to tune the filter over its full range. It is close to the predicted 755 nm of displacement from the simulations (see Fig. 4).

The asymmetric shape of the reflection band of the Bragg mirrors is explained by the model and is due to the excess over etch occurring in the larger openings. For an optical cavity, the
\( Q \) factor is linked to the finesse and to the photon lifetime in the cavity by \( Q = \frac{\lambda}{\text{FWHM} \cdot \nu} = \frac{\nu}{\nu_{\text{FWHM}}} \), where \( \nu \) is the transmitted frequency. At around 1540 nm, the reflection is at its highest value and, as demonstrated in Fig. 3, the FWHM of the peak is the smallest but, since the lifetime in the cavity is longer, divergence losses are higher.

For resonance peaks located between 1520 nm and 1545 nm, the difference between the simulated and the experimental curves increases. Again, this is related to the photon lifetime in the cavity. When it gets longer, the light interacts more with the Bragg mirrors and the losses due to imperfections which are not taken into account by the model (surface roughness, imperfect verticality) are enhanced.

In Fig. 5, it might seem contradictory that the experimental results sometimes present less loss than the simulated results of Fig. 4. The reason is that the simulations of Fig. 4 are performed for a F-P filter having exact nominal dimensions (odd multiple of a quarter of the central wavelength 1550 nm). Experimentally, this case is never reached perfectly. The experimental reflectivity of the mirrors is therefore always lower than the value of Fig. 4. For lower reflectivity, the light is less confined in the resonator and the losses due to divergence increase. In Fig. 5, the same simulations are performed using the real dimensions of the silicon and air layers. In this case, the experimental transmission at the resonance wavelengths is never higher than the simulations.

Moreover, it should be noted that although the measured losses of Fig. 5 are sometimes less important than for the simulations of Fig. 4, the experimental finesse of the F-P resonance is never higher than expected. Again this is related to the lower reflectivity of the Bragg mirrors due to over etching. To summarize, it is not contradictory to obtain lower than expected losses since this happens at the expense of a lower finesse of the F-P.

VI. TUNABLE FIBER LASER

Tuning the wavelength of a laser is one interesting application for a MEMS F-P filter. By introducing the filter into a laser cavity, the emission wavelength can be tuned continuously. In this section, a MEMS-based tunable erbium doped ring fiber laser is demonstrated. A ring laser can be widely tunable, have a narrow emission spectrum and have high output power. The gain provided by the erbium doped fiber can be higher than 20 dB and it spans over the telecommunication C and L bands. In our case, this high gain is required to meet the lasing condition since the F-P filter has high optical loss. A ring fiber laser has no mirror since the light is guided in the optical fiber that is closed onto itself to form a loop. By opening the cavity and aligning the optical fibers on each side of the F-P filter, the filter is fully integrated within the cavity. Fig. 8 shows a schematic of the fiber laser setup. Light from a pump laser diode at 1480 nm is injected through a wave division multiplexing (WDM) coupler into the fiber laser cavity. Six meters of erbium doped fiber (Liekki Er30-4/125) were used. An isolator is placed to insure one way lasing direction. A polarization controller is introduced to improve the laser stability. The fiber laser is continuously tuned over 35 nm from 1539 nm to 1574 nm (Fig. 9). Tuning the laser is realized by tuning the F-P filter as mentioned above. Tuning is controlled by a voltage from 23.9 V to 37.0 V applied to the comb-drive actuator. Because of the high resonance frequency of the MEMS, tuning of the laser is done in tens \( \mu \)s. The variation of the output power across the tuning range is less than 8 dBm. The threshold of the laser is 32.6 mW of absorbed pump power and the slope efficiency is 2.14%. The low slope efficiency is due to the important transmission losses of the F-P filter. Maximal output power (1.8 mW) was obtained using a 50:50 output coupler. The theoretical longitudinal mode spacing in the 8 m long cavity is 25 MHz. The line width of the laser is formed by simultaneous laser emission of many adjacent longitudinal modes [8]. Because of these close longitudinal modes, when changing the selected wavelength with the filter, virtual continuous tuning of the laser is achieved. Even if the spectral width of the filter is relatively large the spectral width of the laser is bellow 0.06 nm (limited by the resolution bandwidth of the optical spectrum analyzer). The tuning range of the laser is limited compared to the tuning range of the filter. The tuning range of the laser is limited by the F-P filter losses, the erbium gain shape and the limited bandwidth of the WDM coupler. Because of the high losses of the filter, the lasing threshold is met only in the spectral region where the combined gain of the doped fiber and transmission of WDM coupler are maximum. Changing the pumping laser wavelength to 980 nm would allow to use a larger bandwidth.
coupler increasing the tuning range. Moreover, using a longer doped fiber length could increase the optical gain in the L-band region. Optimization of the laser cavity and of the filter must be done to expand the tuning range and the output power of the laser. However, to the best of our knowledge, a tunable MEMS-based fiber laser was not demonstrated yet. It is an interesting development for fast and compact tunable fiber lasers.

VII. CONCLUSION

In this paper, we presented a wide range tunable filter. By using a single step etching process, a very compact and integrated tunable F-P filter was fabricated. Optical fibers, actuator, and the optical device were fabricated in one single etching step. Tuning as large as 104 nm in the optical C and L-bands was demonstrated. A mechanical resonance frequency of 14.4 kHz was measured allowing tuning over the whole dynamic range of the filter in few µs. In the second part of this paper, we presented a novel approach to tune a fiber laser with the MEMS actuated F-P filter. By introducing the MEMS F-P filter into a ring fiber laser cavity, a compact tunable fiber laser was demonstrated. The tuning range is 35 nm with a spectral width of less than 0.06 nm.

At this point, the tunable laser is still a basic proof of concept. However, since MEMS allows fast actuation and low cost batch fabrication, our technology opens the path to a wide range of applications in telecommunications, metrology, laser machining, and bio-chemical sensing using high quality integrated tunable fiber lasers.

REFERENCES


Alexandre Poulin studied engineering physics at École Polytechnique de Montréal (EPM), Montréal, QC, Canada. While an undergraduate, he did a one-year-long international exchange to study physics at the École Polytechnique Fédérale de Lausanne, Lausanne, Switzerland. In 2009, he gained an accelerated passage to graduate studies. He is currently pursuing the Masters degree in fast micro-electro-mechanical systems tunable lasers from EPM, under the supervision of Professor Yves-Alain Peter.

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